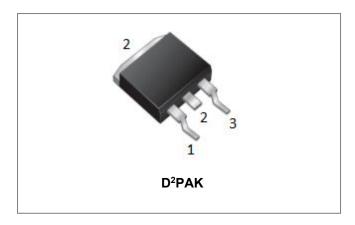


# MBRB60100CT

Technical Data Data Sheet N1103, Rev. C



# **MBRB60100CT SCHOTTKY RECTIFIER**



### **Circuit Diagram**

# Bose common Cathade 0 2

### Features

- 175°C T<sub>J</sub> operation
- Center tap configuration
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Terminals finish: 100% Pure Tin
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

#### **Applications**

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

### Maximum Ratings(limiting values, at 25 °C unless otherwise specified)

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	-	100	V
Average Rectified Forward Current (Per Device)	lf (AV)	Tc=121C, In DC	30(Per Leg) 60(Per Device)	А
Peak One Cycle Non-Repetitive Surge Current(Per Leg)	I <sub>FSM</sub>	8.3ms, Half Sine pulse	280	А

### **Electrical Characteristics:**

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop	V <sub>F1</sub>	@ 30A, Pulse, T <sub>J</sub> = 25 °C	0.85	0.90	V
(Per Leg) *	V <sub>F2</sub>	@ 30A, Pulse, T <sub>J</sub> = 25 °C	0.76	0.81	V
Reverse Current (Per Leg) *	I <sub>R1</sub>	$@V_R = rated V_{R,} T_J = 25 \ ^{\circ}C$	0.01	1.0	mA
	I <sub>R2</sub>	$@V_R = rated V_{R,} T_J = 125 \circ C$	8	20	mA
Junction Capacitance(Per Leg)	Ст	$@V_R = 5V, T_C = 25 \circ C, f_{SIG} = 1MHz$	400	800	pF
Voltage Rate of Change	dv/dt	-	-	10,000	V/μs

\* Pulse width < 300 μs, duty cycle < 2%

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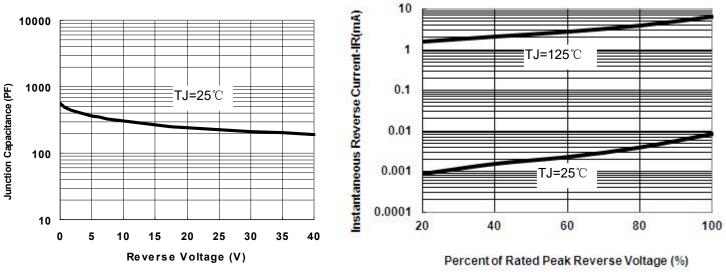
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## Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +175	°C
Storage Temperature	T <sub>stg</sub>	-	-55 to +175	°C
Typical Thermal Resistance Junction to Case(Per Leg)	R <sub>θ</sub> JC	DC operation	2.0	°C/W
Typical Thermal Resistance Junction to Ambient(Per Leg)	$R_{ heta JA}$	DC operation	50	°C/W
Approximate Weight	wt	-	1.85	g
Case Style	D <sup>2</sup> PAK			

## **Ratings and Characteristics Curves**







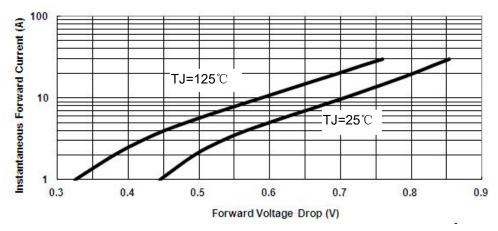


Fig.3-Typical Instantaneous Forward Voltage Characteristics

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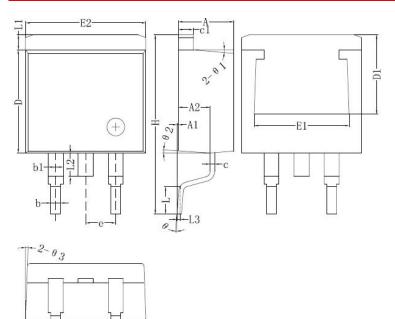


# MBRB60100CT

Technical Data Data Sheet N1103, Rev. C



### Mechanical Dimensions D<sup>2</sup>PAK



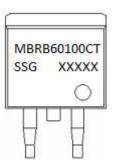
Symbol	Dimensions in millimeters		
	Min.	Max.	
A	4.06	4.83	
A1	0	0.26	
b	0.51	0.99	
b1	1.14	1.78	
с	0.31	0.74	
c1	1.14	1.65	
D	8.38	9.65	
D1	6.4		
E1	6.22		
E2	9.65	10.67	
e	2.54BSC		
Н	14.6	15.88	
L	1.78	2.8	
L1	-	1.68	
L2	-	2.2	
L3	0.255BSC		
Θ	0	8°	

## **Ordering Information**

Device	Package	Shipping
MBRB60100CT	D <sup>2</sup> PAK	800pcs / reel
MBRB60100CTTR	D <sup>2</sup> PAK	800pcs / reel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

## **Marking Diagram**



#### Where XXXXX is YYWWL

MBR

в

60

100 CT

SSG

YΥ

WW

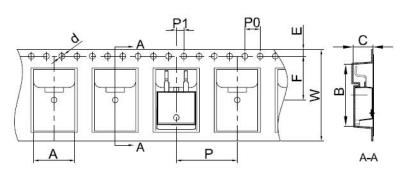
L

= Device Type

- = Package type
- = Forward Current (60A) = Reverse Voltage(100V)
- = Configuration
- = SSG
- = Year = Week
- = Lot Number

Cautions: Molding resin Epoxy resin UL:94V-0

# Carrier Tape Specification D<sup>2</sup>PAK



SYMBOL	Millimeters		
STWIDOL	Min.	Max.	
А	10.70	10.90	
В	16.03	16.23	
С	5.11	5.31	
d	1.45	1.65	
E	1.65	1.85	
F	11.40	11.60	
P0	3.90	4.10	
Р	15.90	16.10	
P1	1.90	2.10	
W	23.90	24.30	

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